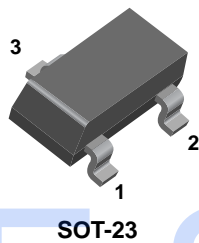




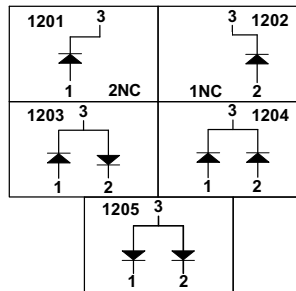
ON Semiconductor®

MMBD1201 / MMBD1202 / MMBD1203 / MMBD1204 / MMBD1205

Small Signal Diodes



Connection Diagram



Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBD1201	24	SOT-23 3L	Tape and Reel
MMBD1202	25	SOT-23 3L	Tape and Reel
MMBD1203	26	SOT-23 3L	Tape and Reel
MMBD1204	27	SOT-23 3L	Tape and Reel
MMBD1205	28	SOT-23 3L	Tape and Reel

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage	100	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
I_{FSM}	Non-Repetitive Peak Forward Surge Current	Pulse Width = 1.0 second	1.0
		Pulse Width = 1.0 microsecond	2.0
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	150	$^\circ\text{C}$

Notes:

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	350	mW
	Derate Above 25°C	2.8	mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	$^\circ\text{C}/\text{W}$

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V_R	Breakdown Voltage	$I_R = 100 \mu\text{A}$	100		V
V_F	Forward Voltage	$I_F = 1.0 \text{ mA}$	550	600	mV
		$I_F = 10 \text{ mA}$	660	740	mV
		$I_F = 100 \text{ mA}$	820	920	mV
		$I_F = 200 \text{ mA}$	0.87	1.0	V
		$I_F = 300 \text{ mA}$		1.1	V
I_R	Reverse Current	$V_R = 20 \text{ V}$		25	nA
		$V_R = 50 \text{ V}$		50	nA
		$V_R = 50 \text{ V}, T_A = 150^\circ\text{C}$		100	μA
C_T	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		2.0	pF
t_{rr}	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA}, R_L = 100 \Omega$		4.0	nS

Typical Performance Characteristics

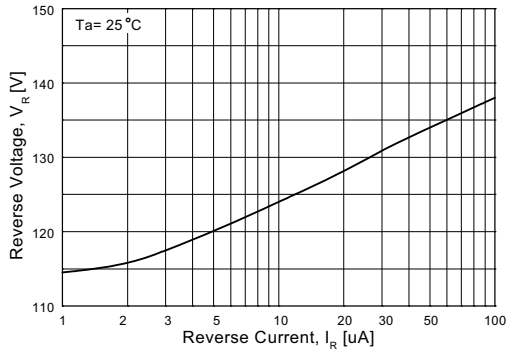


Figure 1. Reverse Voltage vs. Reverse Current V_R @ $I_R = 1.0$ to 100μ A

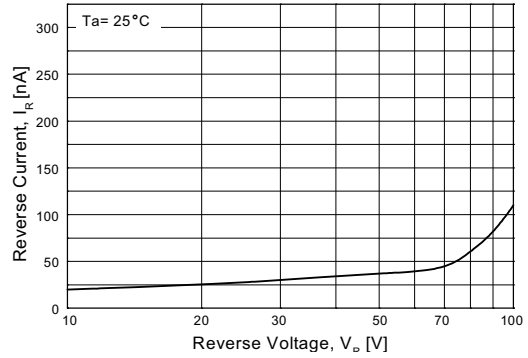


Figure 2. Reverse Current vs. Reverse Voltage I_R @ $V_R = 10$ to 100 V

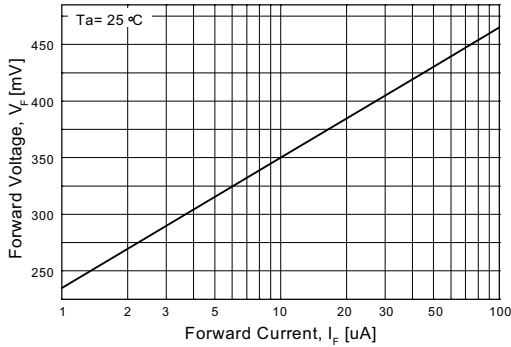


Figure 3. Forward Voltage vs. Forward Current V_F @ $I_F = 1.0$ to 100μ A

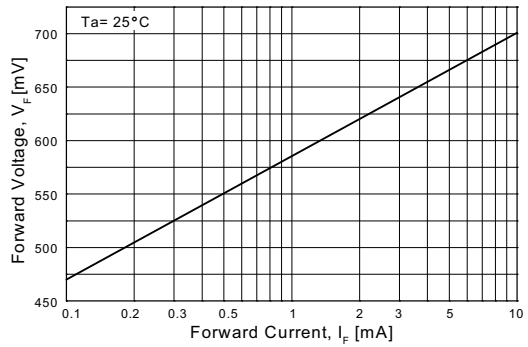


Figure 4. Forward Voltage vs. Forward Current V_F @ $I_F = 0.1$ to 10 mA

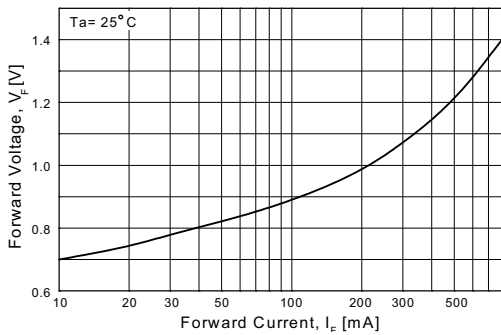


Figure 5. Forward Voltage vs. Forward Current V_F @ $I_F = 10$ to 800 mA

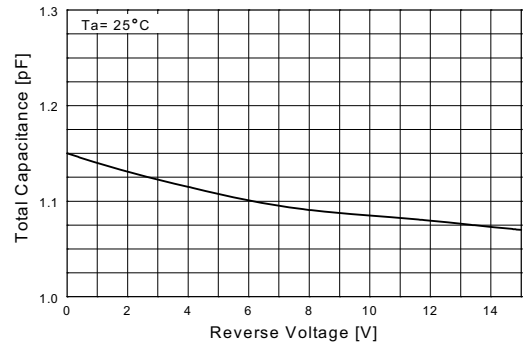


Figure 6. Total Capacitance vs. Reverse Voltage

Typical Performance Characteristics (Continued)

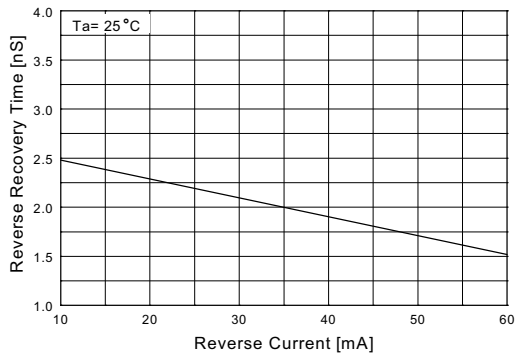


Figure 7. Reverse Recovery Time vs. Reverse Current

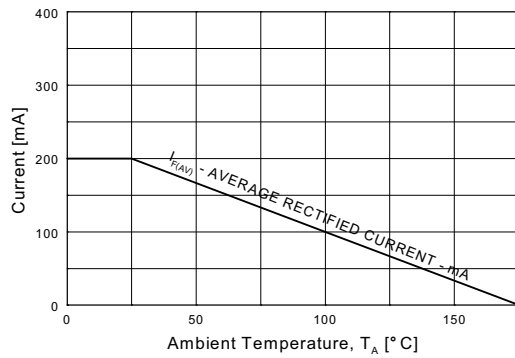


Figure 8. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

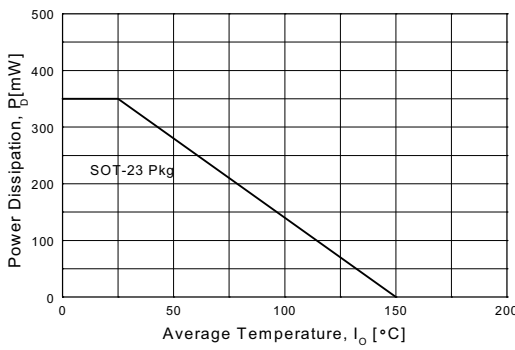
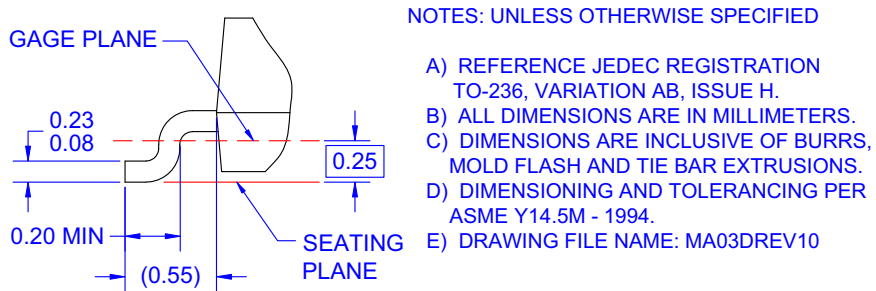
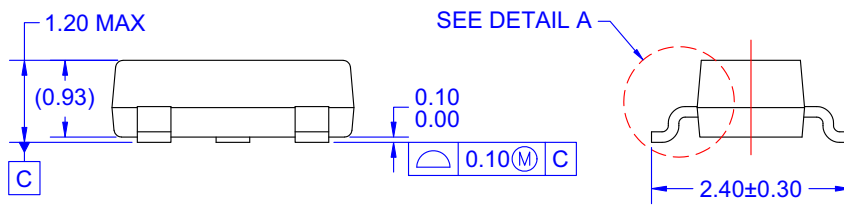
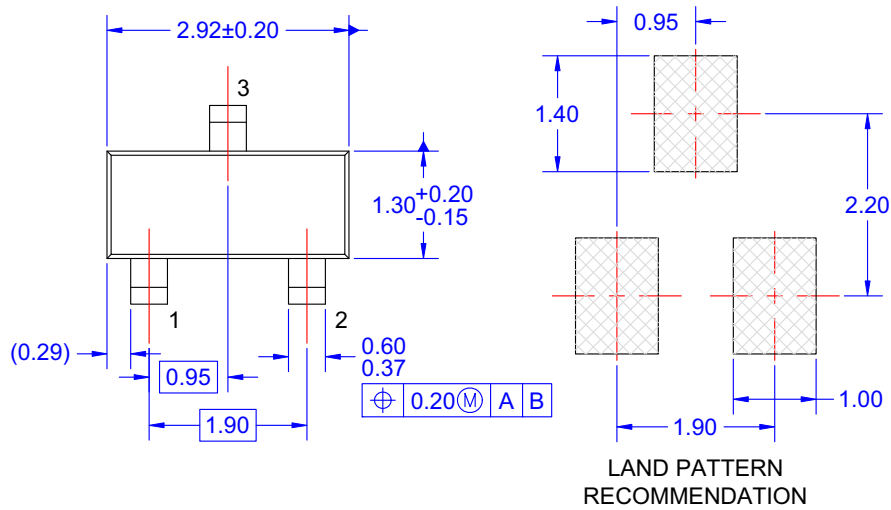


Figure 9. Power Derating Curve

Physical Dimensions



DETAIL A
SCALE: 2X

- NOTES: UNLESS OTHERWISE SPECIFIED
- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
 - B) ALL DIMENSIONS ARE IN MILLIMETERS.
 - C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
 - D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994.
 - E) DRAWING FILE NAME: MA03DREV10

Figure 10. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE

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